



CMRDM3575

**SURFACE MOUNT
N-CHANNEL AND P-CHANNEL
ENHANCEMENT-MODE
COMPLEMENTARY MOSFETS**

FEMTOmini™



SOT-963 CASE

APPLICATIONS:

- Load/Power Switches
- Power Supply Converter Circuits
- Battery Powered Portable Devices

MAXIMUM RATINGS: (TA=25°C)

Drain-Source Voltage	VDS	20	V
Gate-Source Voltage	VGS	8.0	V
Continuous Drain Current (Steady State)	ID	160	mA
Continuous Drain Current ($t_p \leq 5s$)	ID	200	mA
Power Dissipation	PD	125	mW
Operating and Storage Junction Temperature	TJ, Tstg	-65 to +150	°C
Thermal Resistance	ΘJA	1000	°C/W

ELECTRICAL CHARACTERISTICS: (TA=25°C)

SYMBOL	TEST CONDITIONS	N-CH (Q1)			P-CH (Q2)			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
IGSSF	VGS=5.0V, VDS=0V	-	-	100	-	-	100	nA
IGSSR	VGS=5.0V, VDS=0V	-	-	100	-	-	100	nA
IDSS	VDS=5.0V, VGS=0V	-	-	50	-	-	50	nA
IDSS	VDS=16V, VGS=0V	-	-	100	-	-	100	nA
BVDSS	VGS=0V, ID=250µA	20	-	-	20	-	-	V
VGS(th)	VDS=VGS, ID=250µA	0.4	-	1.0	0.4	-	1.0	V
rDS(ON)	VGS=4.5V, ID=100mA	-	1.5	3.0	-	4.0	5.0	Ω
rDS(ON)	VGS=2.5V, ID=50mA	-	2.0	4.0	-	5.5	7.0	Ω
rDS(ON)	VGS=1.8V, ID=20mA	-	3.0	6.0	-	8.0	10	Ω
rDS(ON)	VGS=1.5V, ID=10mA	-	4.0	10	-	11	17	Ω
rDS(ON)	VGS=1.2V, ID=1.0mA	-	7.0	-	-	20	-	Ω
gFS	VDS=5.0V, ID=125mA	-	1.3	-	-	1.3	-	S
Crss	VDS=15V, VGS=0V, f=1.0MHz	-	2.2	-	-	1.0	-	pF
Ciss	VDS=15V, VGS=0V, f=1.0MHz	-	9.0	-	-	12	-	pF
Coss	VDS=15V, VGS=0V, f=1.0MHz	-	3.0	-	-	2.7	-	pF
t _{on}	VDD=10V, VGS=4.5V, ID=200mA	-	40	-	-	60	-	ns
t _{off}	VDD=10V, VGS=4.5V, ID=200mA	-	150	-	-	210	-	ns

Central™
Semiconductor Corp.

DESCRIPTION:

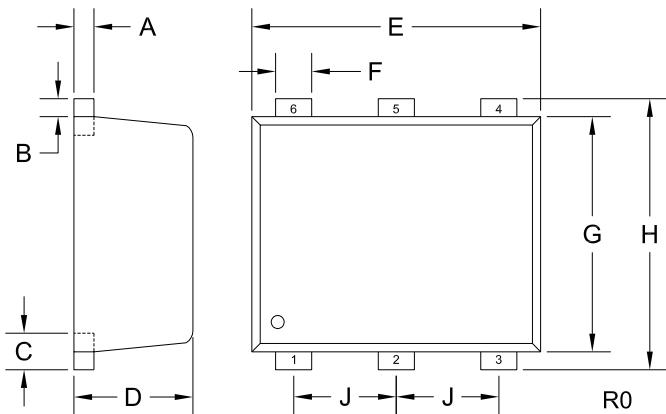
The CENTRAL SEMICONDUCTOR CMRDM3575 consists of complementary N-Channel and P-Channel Enhancement-mode silicon MOSFETs designed for high speed pulsed amplifier and driver applications. These MOSFETs offer Low r_{DS(ON)} and Low Threshold Voltage.

- Device is **Halogen Free** by design

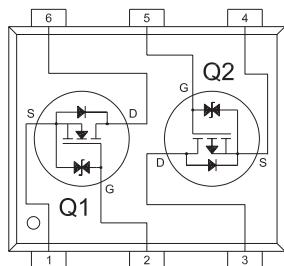
MARKING CODE: CT**FEATURES:**

- Power Dissipation: 125mW
- Low Package Profile: 0.5mm (MAX)
- Low r_{DS(ON)}
- Low Threshold Voltage
- Logic Level Compatible
- Small SOT-963 Surface Mount Package

SOT-963 CASE - MECHANICAL OUTLINE



PIN CONFIGURATION



LEAD CODE:

- 1) SOURCE Q1
- 2) GATE Q1
- 3) DRAIN Q2
- 4) SOURCE Q2
- 5) GATE Q2
- 6) DRAIN Q1

MARKING CODE: CT

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.002	0.006	0.050	0.150
B	0.002	0.006	0.050	0.150
C	0.005	0.007	0.125	0.175
D	0.016	0.020	0.400	0.500
E	0.037	0.041	0.950	1.050
F	0.004	0.008	0.100	0.200
G	0.030	0.033	0.750	0.850
H	0.037	0.041	0.950	1.050
J	0.014		0.350	

SOT-963 (REV: R0)

R0 (25-February 2009)